# **74AUP2G57**

# Low-power dual PCB configurable multiple function gate Rev. 4 — 17 July 2023 Product data sheet

### 1. General description

The 74AUP2G57 is a dual configurable multiple function gate with Schmitt-trigger inputs. Each gate within the device can be configured as any of the following logic functions AND, OR, NAND, NOR, XNOR, inverter and buffer; using the 3-bit input. All inputs can be connected directly to  $V_{CC}$  or GND.

This device ensures very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V.

This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

#### 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- · High noise immunity
- Low static power consumption; I<sub>CC</sub> = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10% of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial power-down mode operation
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

### 3. Ordering information

#### **Table 1. Ordering information**

| Type number | Package           |         |   |           |  |  |  |  |
|-------------|-------------------|---------|---|-----------|--|--|--|--|
|             | Temperature range | Name    | Description   | Version   |  |  |  |  |
| 74AUP2G57DP | -40 °C to +125 °C | TSSOP10 | plastic thin shrink small outline package; 10 leads; body width 3 mm                          | SOT552-1  |  |  |  |  |
| 74AUP2G57GU | -40 °C to +125 °C | XQFN10  | plastic, extremely thin quad flat package; no leads; 10 terminals; body 1.40 × 1.80 × 0.50 mm | SOT1160-1 |  |  |  |  |

### 4. Marking

#### Table 2. Marking

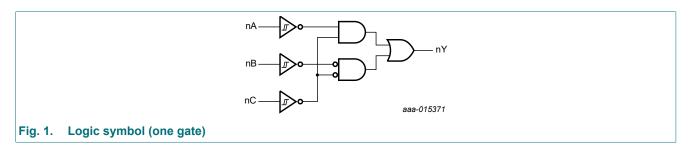
| Type number | Marking code [1] |
|-------------|------------------|
| 74AUP2G57DP | aC               |
| 74AUP2G57GU | aC               |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.



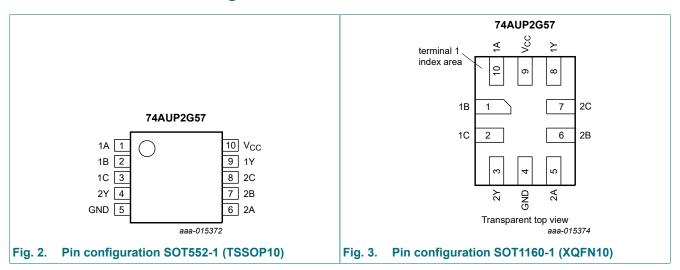
#### Low-power dual PCB configurable multiple function gate

### 5. Functional diagram



### 6. Pinning information

#### 6.1. Pinning



#### 6.2. Pin description

Table 3. Pin description

| Symbol          | Pin      | Description |                |
|-----------------|----------|-------------|----------------|
|                 | SOT552-1 | SOT1160-1   |                |
| 1A, 2A          | 1, 6     | 10, 5       | data input     |
| 1B, 2B          | 2, 7     | 1, 6        | data input     |
| 1C, 2C          | 3, 8     | 2, 7        | data input     |
| 1Y, 2Y          | 9, 4     | 8, 3        | data output    |
| GND             | 5        | 4           | ground (0 V)   |
| V <sub>CC</sub> | 10       | 9           | supply voltage |

#### Low-power dual PCB configurable multiple function gate

### 7. Functional description

#### **Table 4. Function table**

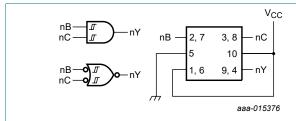
 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

| Input |       |   | Output |
|-------|-------|---|--------|
| nC    | nB nA |   | nY     |
| L     | L     | L | Н      |
| L     | L     | Н | L      |
| L     | Н     | L | Н      |
| L     | Н     | Н | L      |
| Н     | L     | L | L      |
| Н     | L     | Н | L      |
| Н     | Н     | L | Н      |
| Н     | Н     | Н | Н      |

### 7.1. Logic configurations

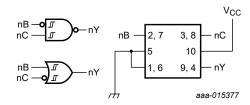
**Table 5. Function selection table** 

| Logic function                        | Figure                |
|---------------------------------------|-----------------------|
| 2-input AND                           | see Fig. 4            |
| 2-input AND with both inputs inverted | see Fig. 7            |
| 2-input NAND with inverted input      | see Fig. 5 and Fig. 6 |
| 2-input OR with inverted input        | see Fig. 5 and Fig. 6 |
| 2-input NOR                           | see Fig. 7            |
| 2-input NOR with both inputs inverted | see Fig. 4            |
| 2-input XNOR                          | see Fig. 8            |
| Inverter                              | see Fig. 9            |
| Buffer                                | see Fig. 10           |



Pin numbers are not valid for SOT1160-1 package

Fig. 4. 2-input AND gate or 2-input NOR gate with both inputs inverted

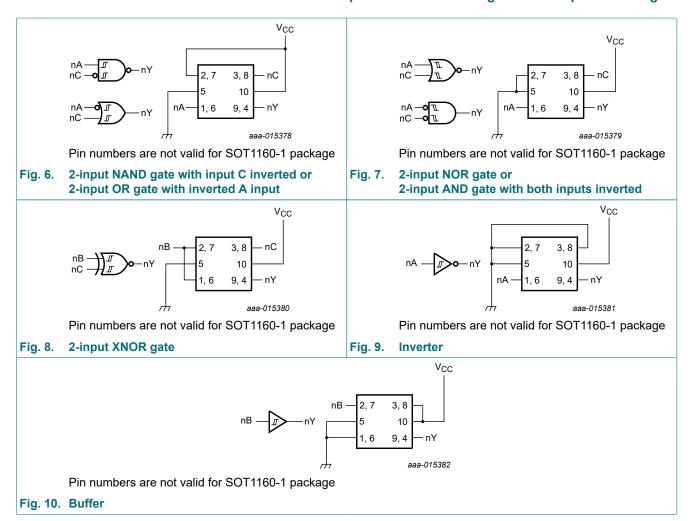


Pin numbers are not valid for SOT1160-1 package

Fig. 5. 2-input NAND gate with input B inverted or 2-input OR gate with inverted C input

Downloaded From Oneyac.com

#### Low-power dual PCB configurable multiple function gate



### 8. Limiting values

#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions                           |     | Min  | Max  | Unit |
|------------------|-------------------------|--------------------------------------|-----|------|------|------|
| V <sub>CC</sub>  | supply voltage          |                                      |     | -0.5 | +4.6 | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < 0 V                 |     | -50  | -    | mA   |
| VI               | input voltage           |                                      | [1] | -0.5 | +4.6 | V    |
| I <sub>OK</sub>  | output clamping current | V <sub>O</sub> < 0 V                 |     | -50  | -    | mA   |
| Vo               | output voltage          | Active mode and Power-down mode      | [1] | -0.5 | +4.6 | V    |
| Io               | output current          | $V_O = 0 V \text{ to } V_{CC}$       |     | -    | ±20  | mA   |
| I <sub>CC</sub>  | supply current          |                                      |     | -    | 50   | mA   |
| $I_{GND}$        | ground current          |                                      |     | -50  | -    | mA   |
| T <sub>stg</sub> | storage temperature     |                                      |     | -65  | +150 | °C   |
| P <sub>tot</sub> | total power dissipation | T <sub>amb</sub> = -40 °C to +125 °C | [2] | -    | 250  | mW   |

- [1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- [2] For SOT552-1 (TSSOP10) packages: P<sub>tot</sub> derates linearly with 8.3 mW/K above 120 °C. For SOT1160-1 (XQFN10) package: P<sub>tot</sub> derates linearly with 7.1 mW/K above 115 °C.

74AUP2G57

#### Low-power dual PCB configurable multiple function gate

### 9. Recommended operating conditions

Table 7. Recommended operating conditions

| Symbol           | Parameter           | Conditions                             | Min | Max             | Unit |
|------------------|---------------------|--|-----|-----------------|------|
| $V_{CC}$         | supply voltage      |  | 0.8 | 3.6             | V    |
| VI               | input voltage       |  | 0   | 3.6             | V    |
| Vo               | output voltage      | Active mode                            | 0   | V <sub>CC</sub> | V    |
|                  |                     | Power-down mode; V <sub>CC</sub> = 0 V | 0   | 3.6             | V    |
| T <sub>amb</sub> | ambient temperature |  | -40 | +125            | °C   |

### 10. Static characteristics

#### **Table 8. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol               | Parameter                            | Conditions  | Min                    | Тур | Max                   | Unit |
|----------------------|--------------------------------------|---|------------------------|-----|-----------------------|------|
| T <sub>amb</sub> = 2 | 5 °C                                 |   |                        |     |                       |      |
| V <sub>OH</sub>      | HIGH-level output                    | $V_I = V_{T+}$ or $V_{T-}$  |                        |     |                       |      |
|                      | voltage                              | $I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V                          | V <sub>CC</sub> - 0.1  | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                         | 0.75 × V <sub>CC</sub> | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                         | 1.11                   | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                        | 1.32                   | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                         | 2.05                   | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                         | 1.9                    | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                         | 2.72                   | -   | -                     | V    |
|                      |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                         | 2.6                    | -   | -                     | V    |
| V <sub>OL</sub>      | LOW-level output                     | $V_I = V_{T+}$ or $V_{T-}$  |                        |     |                       |      |
|                      | voltage                              | $I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V                           | -                      | -   | 0.1                   | V    |
|                      |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                          | -                      | -   | 0.3 × V <sub>CC</sub> | V    |
|                      |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                          | -                      | -   | 0.31                  | V    |
|                      |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                         | -                      | -   | 0.31                  | V    |
|                      |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                          | -                      | -   | 0.31                  | V    |
|                      |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                          | -                      | -   | 0.44                  | V    |
|                      |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                          | -                      | -   | 0.31                  | V    |
|                      |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                          | -                      | -   | 0.44                  | V    |
| I <sub>I</sub>       | input leakage<br>current             | $V_1$ = GND to 3.6 V; $V_{CC}$ = 0 V to 3.6 V                             | -                      | -   | ±0.1                  | μΑ   |
| I <sub>OFF</sub>     | power-off leakage current            | $V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V                         | -                      | -   | ±0.2                  | μΑ   |
| ΔI <sub>OFF</sub>    | additional power-off leakage current | $V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V                    | -                      | -   | ±0.2                  | μΑ   |
| I <sub>CC</sub>      | supply current                       | $V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V      | -                      | -   | 0.5                   | μΑ   |
| ΔI <sub>CC</sub>     | additional supply current            | $V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ | -                      | -   | 40                    | μΑ   |
| Cı                   | input capacitance                    | $V_I$ = GND or $V_{CC}$ ; $V_{CC}$ = 0 V to 3.6 V                         | -                      | 1.1 | -                     | pF   |
| Co                   | output capacitance                   | $V_O = GND$ ; $V_{CC} = 0 V$  | -                      | 1.7 | -                     | pF   |

### Low-power dual PCB configurable multiple function gate

| Symbol                | Parameter                            | Conditions  | Min                   | Тур | Max                   | Unit |
|-----------------------|--------------------------------------|---|-----------------------|-----|-----------------------|------|
| T <sub>amb</sub> = -4 | 40 °C to +85 °C                      |   | '                     |     |                       |      |
| V <sub>OH</sub>       | HIGH-level output                    | $V_I = V_{T+}$ or $V_{T-}$  |                       |     |                       |      |
|                       | voltage                              | $I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V                              | V <sub>CC</sub> - 0.1 | -   | -                     | V    |
|                       |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                             | 0.7 × V <sub>CC</sub> | -   | -                     | V    |
|                       |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                             | 1.03                  | -   | -                     | V    |
|                       |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                            | 1.30                  | -   | -                     | V    |
|                       |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                             | 1.97                  | -   | -                     | V    |
|                       |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                             | 1.85                  | -   | -                     | V    |
|                       |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                             | 2.67                  | -   | -                     | V    |
|                       |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                             | 2.55                  | -   | -                     | V    |
| V <sub>OL</sub>       | LOW-level output                     | $V_I = V_{T+}$ or $V_{T-}$  |                       |     |                       |      |
|                       | voltage                              | $I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V                               | -                     | -   | 0.1                   | V    |
|                       |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                              | -                     | -   | 0.3 × V <sub>CC</sub> | V    |
|                       |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                              | -                     | -   | 0.37                  | V    |
|                       |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                             | -                     | -   | 0.35                  | V    |
|                       |                                      | I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V                              | -                     | -   | 0.33                  | V    |
|                       |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                              | -                     | -   | 0.45                  | V    |
|                       |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                              | -                     | -   | 0.33                  | V    |
|                       |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                              | -                     | -   | 0.45                  | V    |
| l <sub>l</sub>        | input leakage<br>current             | $V_I = GND \text{ to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$ | -                     | -   | ±0.5                  | μA   |
| I <sub>OFF</sub>      | power-off leakage current            | $V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V                             | -                     | -   | ±0.5                  | μA   |
| ΔI <sub>OFF</sub>     | additional power-off leakage current | $V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V                    | -                     | -   | ±0.6                  | μΑ   |
| I <sub>CC</sub>       | supply current                       | $V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V          | -                     | -   | 0.9                   | μA   |
| ΔI <sub>CC</sub>      | additional supply current            | $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$     | -                     | -   | 50                    | μA   |

Downloaded From Oneyac.com

#### Low-power dual PCB configurable multiple function gate

| Symbol                | Parameter                            | Conditions  | Min                    | Тур | Max                    | Unit |
|-----------------------|--------------------------------------|---|------------------------|-----|------------------------|------|
| T <sub>amb</sub> = -4 | 40 °C to +125 °C                     |   |                        |     |                        |      |
| V <sub>OH</sub>       | HIGH-level output                    | $V_I = V_{T+}$ or $V_{T-}$  |                        |     |                        |      |
|                       | voltage                              | $I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V                              | V <sub>CC</sub> - 0.11 | -   | -                      | V    |
|                       |                                      | I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V                             | 0.6 × V <sub>CC</sub>  | -   | -                      | V    |
|                       |                                      | I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V                             | 0.93                   | -   | -                      | V    |
|                       |                                      | I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V                            | 1.17                   | -   | -                      | V    |
|                       |                                      | I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V                             | 1.77                   | -   | -                      | V    |
|                       |                                      | I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V                             | 1.67                   | -   | -                      | V    |
|                       |                                      | I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V                             | 2.40                   | -   | -                      | V    |
|                       |                                      | I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V                             | 2.30                   | -   | -                      | V    |
| V <sub>OL</sub>       | LOW-level output                     | $V_I = V_{T+}$ or $V_{T-}$  |                        |     |                        |      |
|                       | voltage                              | $I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V                               |                        | -   | 0.11                   | V    |
|                       |                                      | I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V                              | -                      | -   | 0.33 × V <sub>CC</sub> | V    |
|                       |                                      | I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V                              | -                      | -   | 0.41                   | V    |
|                       |                                      | I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V                             | -                      | -   | 0.39                   | V    |
|                       |                                      | $I_{O}$ = 2.3 mA; $V_{CC}$ = 2.3 V  | -                      | -   | 0.36                   | V    |
|                       |                                      | I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V                              | -                      | -   | 0.50                   | V    |
|                       |                                      | I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V                              | -                      | -   | 0.36                   | V    |
|                       |                                      | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V                              | -                      | -   | 0.50                   | V    |
| II                    | input leakage<br>current             | $V_I = GND \text{ to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$ | -                      | -   | ±0.75                  | μΑ   |
| I <sub>OFF</sub>      | power-off leakage current            | $V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$   | -                      | -   | ±0.75                  | μΑ   |
| ΔI <sub>OFF</sub>     | additional power-off leakage current | $V_1$ or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V                        | -                      | -   | ±0.75                  | μΑ   |
| I <sub>CC</sub>       | supply current                       | $V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V          | -                      | -   | 1.4                    | μA   |
| Δl <sub>CC</sub>      | additional supply current            | $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$     | -                      | -   | 75                     | μΑ   |

### 11. Dynamic characteristics

#### **Table 9. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit, see Fig. 12.

| Symbol               | Parameter            | Conditions                         | ns 25 °C |         |      |     | °C to<br>5 °C | _   | °C to<br>5 °C | Unit |
|----------------------|----------------------|------------------------------------|----------|---------|------|-----|---------------|-----|---------------|------|
|                      |                      |                                    | Min      | Typ [1] | Max  | Min | Max           | Min | Max           |      |
| C <sub>L</sub> = 5 p | F                    |                                    | <u>'</u> |         |      |     |               |     |               |      |
| t <sub>pd</sub>      | propagation<br>delay | nA, nB and nC to nY; see Fig. 11   | [2]      |         |      |     |               |     |               |      |
|                      |                      | V <sub>CC</sub> = 0.8 V            | -        | 22.6    | -    | -   | -             | -   | -             | ns   |
|                      |                      | V <sub>CC</sub> = 1.1 V to 1.3 V   | 2.8      | 6.5     | 12.6 | 2.5 | 13.0          | 2.5 | 13.2          | ns   |
|                      |                      | V <sub>CC</sub> = 1.4 V to 1.6 V   | 2.2      | 4.6     | 7.6  | 2.5 | 8.2           | 2.5 | 8.6           | ns   |
|                      |                      | V <sub>CC</sub> = 1.65 V to 1.95 V | 2.1      | 3.9     | 6.2  | 2.0 | 6.8           | 2.0 | 7.2 n         | ns   |
|                      |                      | V <sub>CC</sub> = 2.3 V to 2.7 V   | 2.0      | 3.1     | 4.5  | 1.8 | 5.1           | 1.8 | 5.3           | ns   |
|                      |                      | V <sub>CC</sub> = 3.0 V to 3.6 V   | 1.8      | 2.8     | 3.9  | 1.5 | 4.1           | 1.5 | 4.3           | ns   |

#### Low-power dual PCB configurable multiple function gate

| Symbol               | Parameter       | Conditions   | 25 °C |         |      | °C to<br>5 °C |          | °C to<br>5 °C | Unit |    |
|----------------------|-----------------|--|-------|---------|------|---------------|----------|---------------|------|----|
|                      |                 |  | Min   | Typ [1] | Max  | Min           | Max      | Min           | Max  |    |
| C <sub>L</sub> = 10  | pF              |  |       |         |      |               |          |               |      |    |
| t <sub>pd</sub>      | propagation     | nA, nB and nC to nY; see Fig. 11 [2]                       |       |         |      |               |          |               |      |    |
|                      | delay           | V <sub>CC</sub> = 0.8 V                                    | -     | 26.1    | -    | -             | -        | -             | -    | ns |
|                      |                 | V <sub>CC</sub> = 1.1 V to 1.3 V                           | 3.2   | 7.3     | 14.4 | 2.8           | 14.9     | 2.8           | 15.2 | ns |
|                      |                 | V <sub>CC</sub> = 1.4 V to 1.6 V                           | 2.6   | 5.2     | 8.7  | 2.8           | 9.3      | 2.8           | 9.8  | ns |
|                      |                 | V <sub>CC</sub> = 1.65 V to 1.95 V                         | 2.5   | 4.5     | 7.0  | 2.2           | 7.8      | 2.2           | 8.2  | ns |
|                      |                 | V <sub>CC</sub> = 2.3 V to 2.7 V                           | 2.4   | 3.7     | 5.2  | 2.1           | 5.9      | 2.1           | 6.2  | ns |
|                      |                 | V <sub>CC</sub> = 3.0 V to 3.6 V                           | 2.3   | 3.4     | 4.6  | 1.9           | 4.9      | 1.9           | 5.1  | ns |
| C <sub>L</sub> = 15  | pF              |  |       |         |      |               |          |               |      |    |
| t <sub>pd</sub>      | propagation     | nA, nB and nC to nY; see Fig. 11 [2]                       |       |         |      |               |          |               |      |    |
|                      | delay           | V <sub>CC</sub> = 0.8 V                                    | -     | 31.6    | -    | -             | -        | -             | -    | ns |
|                      |                 | V <sub>CC</sub> = 1.1 V to 1.3 V                           | 3.4   | 8.0     | 15.7 | 3.1           | 16.7     | 3.1           | 17.0 | ns |
|                      |                 | V <sub>CC</sub> = 1.4 V to 1.6 V                           | 2.8   | 5.7     | 9.4  | 3.1           | 10.4     | 3.1           | 10.9 | ns |
|                      |                 | V <sub>CC</sub> = 1.65 V to 1.95 V                         | 2.6   | 4.9     | 7.7  | 2.5           | 8.7      | 2.5           | 9.2  | ns |
|                      |                 | V <sub>CC</sub> = 2.3 V to 2.7 V                           | 2.6   | 4.1     | 5.7  | 2.4           | 6.5      | 2.4           | 6.9  | ns |
|                      |                 | V <sub>CC</sub> = 3.0 V to 3.6 V                           | 2.5   | 3.8     | 5.0  | 2.2           | 5.5      | 2.2           | 5.7  | ns |
| C <sub>L</sub> = 30  | pF              |  |       |         |      |               | <b>'</b> |               |      | •  |
| t <sub>pd</sub>      | propagation     | nA, nB and nC to nY; see Fig. 11 [2]                       |       |         |      |               |          |               |      |    |
|                      | delay           | V <sub>CC</sub> = 0.8 V                                    | -     | 37.8    | -    | -             | -        | -             | -    | ns |
|                      |                 | V <sub>CC</sub> = 1.1 V to 1.3 V                           | 4.6   | 10.4    | 20.9 | 3.9           | 21.8     | 3.9           | 22.3 | ns |
|                      |                 | V <sub>CC</sub> = 1.4 V to 1.6 V                           | 3.6   | 7.4     | 12.2 | 3.8           | 13.4     | 3.8           | 14.1 | ns |
|                      |                 | V <sub>CC</sub> = 1.65 V to 1.95 V                         | 3.5   | 6.2     | 9.9  | 3.1           | 11.1     | 3.1           | 11.8 | ns |
|                      |                 | V <sub>CC</sub> = 2.3 V to 2.7 V                           | 3.4   | 5.2     | 7.4  | 3.1           | 8.3      | 3.1           | 8.8  | ns |
|                      |                 | V <sub>CC</sub> = 3.0 V to 3.6 V                           | 3.2   | 4.9     | 6.6  | 2.8           | 7.0      | 2.8           | 7.4  | ns |
| C <sub>L</sub> = 5 p | F, 10 pF, 15 pF | and 30 pF  |       |         |      |               | <u> </u> |               | '    | _  |
| C <sub>PD</sub>      | power           | $f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [3] [4] |       |         |      |               |          |               |      |    |
|                      | dissipation     | V <sub>CC</sub> = 0.8 V                                    | -     | 2.6     | -    | -             | -        | -             | -    | pF |
|                      | capacitance     | V <sub>CC</sub> = 1.1 V to 1.3 V                           | -     | 2.8     | -    | -             | -        | -             | -    | pF |
|                      |                 | V <sub>CC</sub> = 1.4 V to 1.6 V                           | -     | 2.9     | -    | -             | -        | -             | -    | pF |
|                      |                 | V <sub>CC</sub> = 1.65 V to 1.95 V                         | -     | 3.1     | -    | -             | -        | -             | -    | pF |
|                      |                 | V <sub>CC</sub> = 2.3 V to 2.7 V                           | -     | 3.7     | -    | -             | -        | -             | -    | pF |
|                      |                 | V <sub>CC</sub> = 3.0 V to 3.6 V                           | -     | 4.3     | -    | -             | -        | -             | -    | pF |
|                      | 1               | - I  |       |         |      |               |          |               |      |    |

All typical values are measured at nominal V<sub>CC</sub>.

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;  $\Sigma (C_L \times V_{CC}^{\ 2} \times f_o) = \text{sum of the outputs}.$ 

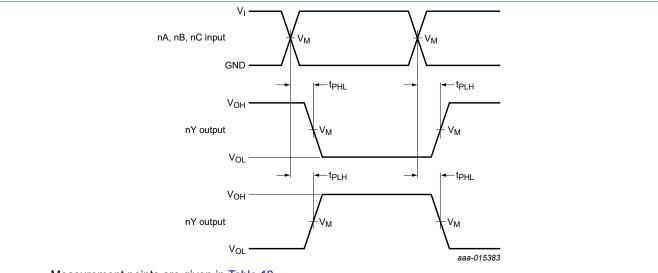
<sup>[2]</sup> 

 $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ . All specified values are the average typical values over all stated loads.

<sup>[4]</sup>  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu$ W).  $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

#### Low-power dual PCB configurable multiple function gate

#### 11.1. Waveform and test circuit



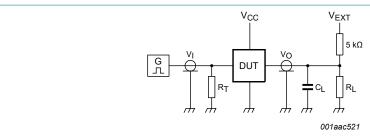
Measurement points are given in Table 10.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical output voltage levels that occur with the output load.

Fig. 11. Input nA, nB and nC to output nY propagation delay times

**Table 10. Measurement points** 

| Supply voltage  | Output                | Input                 |                 |             |  |  |
|-----------------|-----------------------|-----------------------|-----------------|-------------|--|--|
| V <sub>CC</sub> | V <sub>M</sub>        | V <sub>M</sub>        | VI              | $t_r = t_f$ |  |  |
| 0.8 V to 3.6 V  | 0.5 × V <sub>CC</sub> | 0.5 × V <sub>CC</sub> | V <sub>CC</sub> | ≤ 3.0 ns    |  |  |



Test data is given in Table 11.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

V<sub>EXT</sub> = External voltage for measuring switching times.

Fig. 12. Test circuit for measuring switching times

Table 11. Test data

| Supply voltage                 | Load                         |                    | V <sub>EXT</sub>                    |                                     |                                     |  |  |
|--------------------------------|------------------------------|--------------------|-------------------------------------|-------------------------------------|-------------------------------------|--|--|
| V <sub>CC</sub> C <sub>L</sub> |                              | R <sub>L</sub> [1] | t <sub>PLH</sub> , t <sub>PHL</sub> | t <sub>PZH</sub> , t <sub>PHZ</sub> | t <sub>PZL</sub> , t <sub>PLZ</sub> |  |  |
| 0.8 V to 3.6 V                 | 5 pF, 10 pF, 15 pF and 30 pF | 5 kΩ or 1 MΩ       | open                                | GND                                 | 2 × V <sub>CC</sub>                 |  |  |

[1] For measuring enable and disable times,  $R_L$  = 5 k $\Omega$ .

For measuring propagation delays, set-up and hold times, and pulse width,  $R_{L}$  = 1  $\mbox{M}\Omega.$ 

74AUP2G57

#### Low-power dual PCB configurable multiple function gate

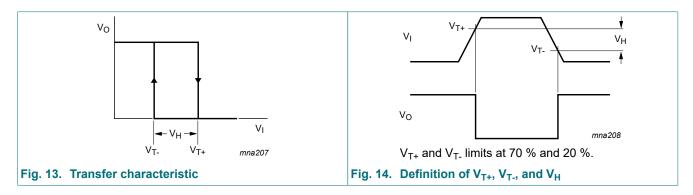
### 12. Transfer characteristics

#### **Table 12. Transfer characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 12.

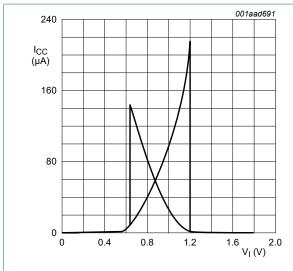
| Symbol          | Parameter          | Conditions   |      | 25 °C |      | -40 °C to | o +85 °C | -40 °C to | +125 °C | Unit                                |
|-----------------|--------------------|--|------|-------|------|-----------|----------|-----------|---------|-------------------------------------|
|                 |                    |  | Min  | Тур   | Max  | Min       | Max      | Min       | Max     |                                     |
|                 | positive-going     | see Fig. 13 and Fig. 14  |      |       |      |           |          |           |         |                                     |
|                 | threshold voltage  | V <sub>CC</sub> = 0.8 V  | 0.30 | -     | 0.60 | 0.30      | 0.60     | 0.30      | 0.62    | V                                   |
|                 |                    | V <sub>CC</sub> = 1.1 V  | 0.53 | -     | 0.90 | 0.53      | 0.90     | 0.53      | 0.92    | V                                   |
|                 |                    | V <sub>CC</sub> = 1.4 V  | 0.74 | -     | 1.11 | 0.74      | 1.11     | 0.74      | 1.13    | V                                   |
|                 |                    | V <sub>CC</sub> = 1.65 V   | 0.91 | -     | 1.29 | 0.91      | 1.29     | 0.91      | 1.31    | V                                   |
|                 |                    | V <sub>CC</sub> = 2.3 V  | 1.37 | -     | 1.77 | 1.37      | 1.77     | 1.37      | 1.80    | V                                   |
|                 |                    | V <sub>CC</sub> = 3.0 V  | 1.88 | -     | 2.29 | 1.88      | 2.29     | 1.88      | 2.32    | V                                   |
| V <sub>T-</sub> | negative-going     | see Fig. 13 and Fig. 14  |      |       |      |           |          |           |         |                                     |
|                 | threshold voltage  | V <sub>CC</sub> = 0.8 V  | 0.10 | -     | 0.60 | 0.10      | 0.60     | 0.10      | 0.60    | .80 V .32 V .60 V .65 V .75 V .84 V |
|                 |                    | V <sub>CC</sub> = 1.1 V  | 0.26 | -     | 0.65 | 0.26      | 0.65     | 0.26      | 0.65    | V                                   |
|                 |                    | V <sub>CC</sub> = 1.4 V  | 0.39 | -     | 0.75 | 0.39      | 0.75     | 0.39      | 0.75    | V                                   |
|                 |                    | V <sub>CC</sub> = 1.65 V   | 0.47 | -     | 0.84 | 0.47      | 0.84     | 0.47      | 0.84    | V                                   |
|                 |                    | V <sub>CC</sub> = 2.3 V  | 0.69 | -     | 1.04 | 0.69      | 1.04     | 0.69      | 1.04    | V                                   |
|                 |                    | V <sub>CC</sub> = 3.0 V  | 0.88 | -     | 1.24 | 0.88      | 1.24     | 0.88      | 1.24    | V                                   |
| V <sub>H</sub>  | hysteresis voltage | (V <sub>T+</sub> - V <sub>T-</sub> ); see <u>Fig. 13</u> ,<br><u>Fig. 14</u> , <u>Fig. 15</u> and <u>Fig. 16</u> |      |       |      |           |          |           |         |                                     |
|                 |                    | V <sub>CC</sub> = 0.8 V  | 0.07 | -     | 0.50 | 0.07      | 0.50     | 0.07      | 0.50    | V                                   |
|                 |                    | V <sub>CC</sub> = 1.1 V  | 0.08 | -     | 0.46 | 0.08      | 0.46     | 0.08      | 0.46    | V                                   |
|                 |                    | V <sub>CC</sub> = 1.4 V  | 0.18 | -     | 0.56 | 0.18      | 0.56     | 0.18      | 0.56    | V                                   |
|                 |                    | V <sub>CC</sub> = 1.65 V   | 0.27 | -     | 0.66 | 0.27      | 0.66     | 0.27      | 0.66    | V                                   |
|                 |                    | V <sub>CC</sub> = 2.3 V  | 0.53 | -     | 0.92 | 0.53      | 0.92     | 0.53      | 0.92    | V                                   |
|                 |                    | V <sub>CC</sub> = 3.0 V  | 0.79 | -     | 1.31 | 0.79      | 1.31     | 0.79      | 1.31    | V                                   |

#### 12.1. Waveform transfer characteristics



74AUP2G57

#### Low-power dual PCB configurable multiple function gate



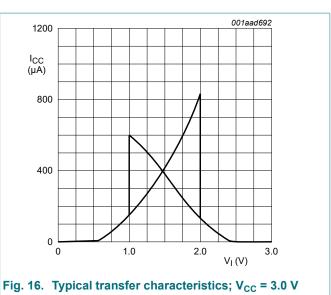


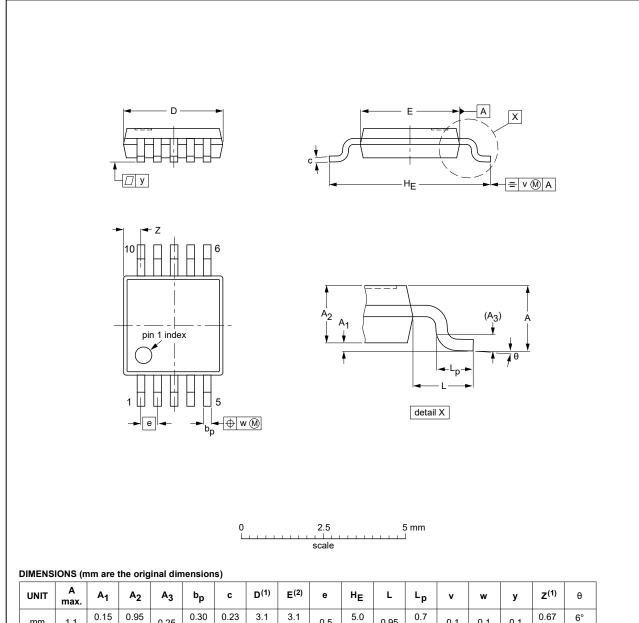
Fig. 15. Typical transfer characteristics;  $V_{CC}$  = 1.8 V

#### Low-power dual PCB configurable multiple function gate

### 13. Package outline

#### TSSOP10: plastic thin shrink small outline package; 10 leads; body width 3 mm

SOT552-1



| UNIT | A<br>max. | A <sub>1</sub> | A <sub>2</sub> | А3   | bp           | С            | D <sup>(1)</sup> | E <sup>(2)</sup> | е   | HE         | L    | Lp         | v   | w   | у   | Z <sup>(1)</sup> | θ        |
|------|-----------|----------------|----------------|------|--------------|--------------|------------------|------------------|-----|------------|------|------------|-----|-----|-----|------------------|----------|
| mm   | 1.1       | 0.15<br>0.05   | 0.95<br>0.80   | 0.25 | 0.30<br>0.15 | 0.23<br>0.15 | 3.1<br>2.9       | 3.1<br>2.9       | 0.5 | 5.0<br>4.8 | 0.95 | 0.7<br>0.4 | 0.1 | 0.1 | 0.1 | 0.67<br>0.34     | 6°<br>0° |

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

| OUTLINE  |     | REFER | RENCES |  |            |                                 |  |  |
|----------|-----|-------|--------|--|------------|---------------------------------|--|--|
| VERSION  | IEC | JEDEC | JEITA  |  | PROJECTION | ISSUE DATE                      |  |  |
| SOT552-1 |     |       |        |  |            | <del>99-07-29</del><br>03-02-18 |  |  |

Fig. 17. Package outline SOT552-1 (TSSOP10)

74AUP2G57

**Product data sheet** 

#### Low-power dual PCB configurable multiple function gate

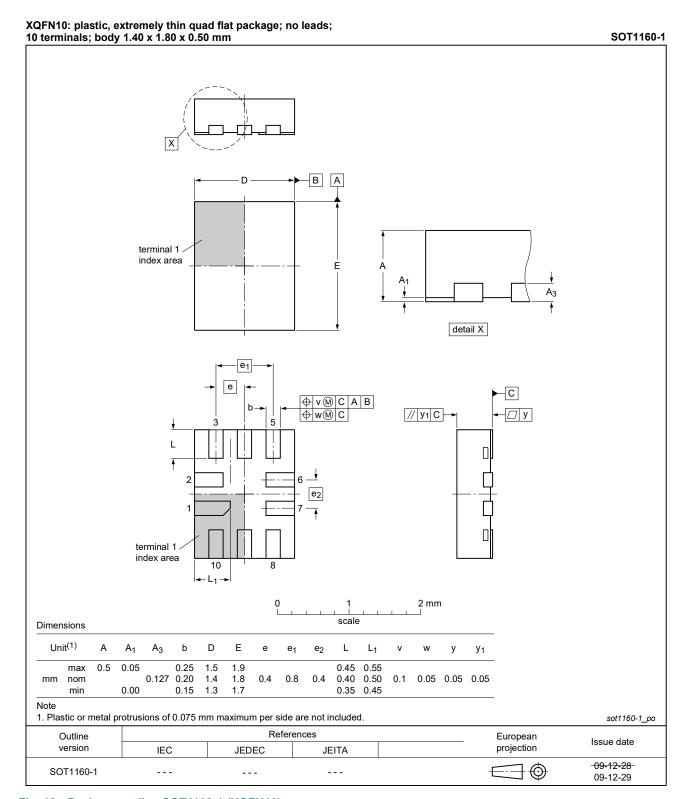


Fig. 18. Package outline SOT1160-1 (XQFN10)

#### Low-power dual PCB configurable multiple function gate

### 14. Abbreviations

#### **Table 13. Abbreviations**

| Acronym | Description             |
|---------|-------------------------|
| CDM     | Charged Device Model    |
| DUT     | Device Under Test       |
| ESD     | ElectroStatic Discharge |
| НВМ     | Human Body Model        |
| PCB     | Printed Circuit Board   |

### 15. Revision history

#### **Table 14. Revision history**

| Document ID    | Release date                          | Data sheet status   | Change notice                       | Supersedes                       |  |  |  |  |
|----------------|---------------------------------------|---|-------------------------------------|----------------------------------|--|--|--|--|
| 74AUP2G57 v.4  | 20230717                              | Product data sheet  | -                                   | 74AUP2G57 v.3                    |  |  |  |  |
| Modifications: | Section 2: E                          | SD specification updated a  | according to the la                 | itest JEDEC standard.            |  |  |  |  |
| 74AUP2G57 v.3  | 20210507                              | Product data sheet  | -                                   | 74AUP2G57 v.2                    |  |  |  |  |
| Modifications: | guidelines of Legal texts Type number | of this data sheet has beer<br>of Nexperia.<br>have been adapted to the i<br>er 74AUP2G57GF (SOT10<br>Derating values for P <sub>tot</sub> tota   | new company nan<br>81-2 / XSON10) r | ne where appropriate.<br>emoved. |  |  |  |  |
| 74AUP2G57 v.2  | 20151202                              | Product data sheet  | -                                   | 74AUP2G57 v.1                    |  |  |  |  |
| Modifications: | 125 °C.                               | <ul> <li>Maximum value temperature range TSSOP10 (74AUP2G57DP) changed from 85 °C to 125 °C.</li> <li>Removed 74AUP2G57GM (SOT1049-3).</li> </ul> |                                     |                                  |  |  |  |  |
| 74AUP2G57 v.1  | 20141104                              | Product data sheet  | -                                   | -                                |  |  |  |  |

#### Low-power dual PCB configurable multiple function gate

### 16. Legal information

#### **Data sheet status**

| Document status [1][2]         | Product<br>status [3] | Definition  |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet   | Development           | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification         | This document contains data from the preliminary specification.                       |
| Product [short]<br>data sheet  | Production            | This document contains the product specification.                                     |

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <a href="https://www.nexperia.com">https://www.nexperia.com</a>.

#### **Definitions**

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

#### **Disclaimers**

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal

injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nexperia.com/profile/terms">http://www.nexperia.com/profile/terms</a>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by sustained.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

#### **Trademarks**

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

74AUP2G57

All information provided in this document is subject to legal disclaimers.

© Nexperia B.V. 2023. All rights reserved

#### Low-power dual PCB configurable multiple function gate

# Contents

| 1. General description                  | <i>'</i> |
|---|----------|
| 2. Features and benefits                | ······ ′ |
| 3. Ordering information                 | 1        |
| 4. Marking                              | 1        |
| 5. Functional diagram                   | 2        |
| 6. Pinning information                  |          |
| 6.1. Pinning                            |          |
| 6.2. Pin description                    |          |
| 7. Functional description               |          |
| 7.1. Logic configurations               |          |
| 8. Limiting values                      |          |
| Recommended operating conditions        |          |
| 10. Static characteristics              |          |
| 11. Dynamic characteristics             |          |
| 11.1. Waveform and test circuit         |          |
| 12. Transfer characteristics            |          |
| 12.1. Waveform transfer characteristics |          |
| 13. Package outline                     |          |
| 14. Abbreviations                       |          |
| 15. Revision history                    |          |
| 16. Legal information                   |          |
|   |          |

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 17 July 2023

<sup>©</sup> Nexperia B.V. 2023. All rights reserved

# 单击下面可查看定价,库存,交付和生命周期等信息

>>Nexperia(安世)